<u>onsemi</u>

TinyLogic UHS Dual 2-Input NAND Gate with Schmitt Trigger Inputs

NC7WZ132

Description

The NC7WZ132 is a dual 2–Input NAND Gate with Schmitt-trigger inputs from **onsemi**'s Ultra High Speed Series of TinyLogic. The device is fabricated with advanced CMOS technology to achieve ultra high speed with high output drive while maintaining low static power dissipation over a broad V_{CC} operating range. The device is specified to operate over the 1.65 V to 5.5 V V_{CC} operating range. The inputs and output are high impedance when V_{CC} is 0 V. Inputs tolerate voltages up to 5.5 V independent of V_{CC} operating voltage. Schmitt trigger inputs achieve typically 1 V hysteresis between the positive–going and negative–going input threshold voltage at 5 V V_{CC} .

Features

- Space Saving US8 Surface Mount Package
- MicroPak[™] Leadless Package
- Ultra High Speed: t_{PD} = 3.1 ns Typ. into 50 pF at 5 V V_{CC}
- High Output Drive: ±24 mA at 3 V V_{CC}
- Broad V_{CC} Operating Range: 1.65 V to 5.5 V
- Matches the Performance of LCX when Operated at 3.3 V V_{CC}
- Power Down High Impedance Inputs / Output
- Overvoltage Tolerant Inputs Facilitate 5 V to 3 V Translation
- Proprietary Noise / EMI Reduction Circuitry Implemented
- Schmitt Trigger Inputs are Tolerant of Slow Changing Input Signals
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

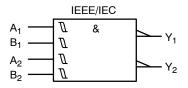
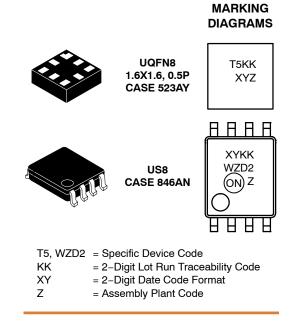


Figure 1. Logic Symbol



ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

Connection Diagram

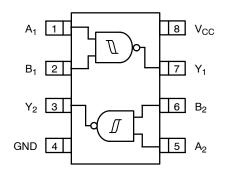
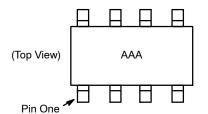


Figure 2. Connection Diagram (Top View)



AAA represents Product Code Top Mark - see ordering code

NOTE: Orientation of Top Mark determines Pin One location. Read the top product code mark left to right, Pin One is the lower left pin (see diagram).

Figure 3. Pin One Orientation Diagram

PIN DESCRIPTION

Pin Names	Description
A _n , B _n	Inputs
Y _n	Output

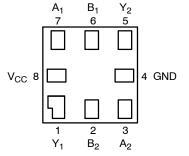


Figure 4. Pad Assignments for MicroPak (Top Thru View)

FUNCTION TABLE	$(Y = \overline{AB})$
-----------------------	-----------------------

Inp	Output	
А	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

H = HIGH Logic Level L = LOW Logic Level

ABSOLUTE MAXIMUM RATINGS

Symbol	Param	eter	Min	Max	Unit
V _{CC}	Supply Voltage		-0.5	6.5	V
V _{IN}	DC Input Voltage		-0.5	6.5	V
V _{OUT}	DC Output Voltage		-0.5	6.5	V
Ι _{ΙΚ}	DC Input Diode Current	V _{IN} < 0 V	-	-50	mA
Ι _{ΟΚ}	DC Output Diode Current	V _{OUT} < 0 V	-	-50	mA
I _{OUT}	DC Output Current	-	±50	mA	
I _{CC} / I _{GND}	DC V _{CC} / GND Current		-	±100	mA
T _{STG}	Storage Temperature		-65	+150	°C
TJ	Junction Temperature under Bias		-	150	°C
ΤL	Junction Lead Temperature (Sold	-	260	°C	
PD	Power Dissipation in Still Air US8		-	500	mW
		MicroPak-8	-	539	mW

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parame	Min	Мах	Unit	
V _{CC}	Supply Voltage Operating	1.65	5.5	V	
	Supply Voltage Data Retention	1.5	5.5		
V _{IN}	Input Voltage	0	5.5	V	
V _{OUT}	Output Voltage	0	V _{CC}	V	
T _A	Operating Temperature	-40	+85	°C	
θ_{JA}	Thermal Resistance US8		-	250	°C/W
		MicroPak-8	-	232	°C/W

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 1. Unused inputs must be held HIGH or LOW. They may not float.

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DC ELECTICAL CHARACTERISTICS

					т	A = +25°	С	T _A = -40	to +85°C						
Symbol	Parameter	V _{CC} (V)	Co	onditions	Min	Тур	Max	Min	Max	Unit					
VP	Positive Threshold	1.65			-	0.99	1.4	-	1.4	V					
	Voltage	2.3	-		-	1.39	1.8	-	1.8						
		3.0			-	1.77	2.2	-	2.2	1					
		4.5			-	2.49	3.1	-	3.1	1					
		5.5			-	2.96	3.6	-	3.6	1					
V _N	Negative Threshold	1.65			0.2	0.53	_	0.2	-	V					
	Voltage	2.3			0.4	0.78	_	0.4	-	1					
		3.0			0.6	1.02	_	0.6	-	1					
		4.5			1.0	1.48	_	1.0	-	1					
		5.5			1.2	1.76	_	1.2	-	1					
V _H	Hysteresis Voltage	1.65			0.15	0.46	0.9	0.15	0.9	V					
		2.3			0.25	0.61	1.1	0.25	1.1	1					
		3.0			0.4	0.75	1.2	0.4	1.2	1					
		4.5	-		0.6	1.01	1.5	0.6	1.5	1					
		5.5				0.7	1.20	1.7	0.7	1.7	1				
V _{OH}	OH HIGH Level Output	1.65	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100 μA	1.55	1.65	_	1.55	-	V					
Voltage	2.3	or V _{IL}		2.2	2.3	_	2.2	-	1						
	3.0			2.9	3.0	_	2.9	-	1						
		4.5	1		4.4	4.5	_	4.4	-	1					
		1.65	1	I _{OH} =4 mA	1.29	1.52	_	1.29	-	1					
		2.3	1	I _{OH} =8 mA	1.9	2.15	_	1.9	-	1					
		3.0	-						I _{OH} = -16 mA	2.4	2.80	_	2.4	-	1
		3.0												I _{OH} =24 mA	2.3
		4.5	1	I _{OH} =32 mA	3.8	4.20	_	3.8	-	1					
V _{OL}	LOW Level Output	1.65	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	-	0.0	0.10	-	0.10	V					
	Voltage	2.3	or V _{IL}		-	0.0	0.10	-	0.10	1					
		3.0			-	0.0	0.10	-	0.10	1					
		4.5			-	0.0	0.10	-	0.10	1					
		1.65		I _{OL} = 4 mA	-	0.08	0.24	_	0.24	1					
		2.3		I _{OL} = 8 mA	-	0.10	0.3	_	0.3	1					
		3.0		I _{OL} = 16 mA	-	0.15	0.4	-	0.4	4					
		3.0	-	I _{OL} = 24 mA	-	0.22	0.55	-	0.55						
		4.5		I _{OL} = 32 mA	-	0.22	0.55	-	0.55						
I _{IN}	Input Leakage Current	1.65 to 5.5	V _{IN} = 5.5 V		-	-	±0.1	-	±1	μA					
I _{OFF}	Power Off Leakage Current	0.0	V _{IN} or V _{OU}		-	-	1	-	10	μ/					
I _{CC}	Quiescent Supply Current	1.65 to 5.5	V _{IN} = 5.5 V	, GND	-	-	1	-	10	μA					

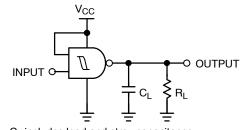
NC7WZ132

AC ELECTRICAL CHARACTERISTICS

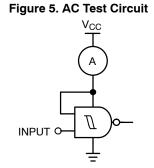
				$T_A = +25^{\circ}C$ $T_A = -40 \text{ to } +85^{\circ}C$			to +85°C		
Symbol	Parameter	V _{CC} (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t _{PLH} , t _{PHL}	Propagation Delay	1.8 ±0.15	C _L = 15 pF,	-	7,1	13.0	-	13.5	ns
	(Figure 5, 7)	2.5 ±0.2	$R_L = 1 M\Omega$	-	4.5	7.5	-	8.0	
		3.3 ±0.3		-	3.4	5.0	-	5.5	
		5.0 ±0.5		-	2.6	3.8	-	4.2	
		3.3 ±0.3	C _L = 50 pF,	-	4.0	5.8	-	6.3	ns
		5.0 ±0.5	$R_L = 500 \Omega$	-	3.1	4.5	-	4.9	
C _{IN}	Input Capacitance	0		-	2.5	-	-	-	pF
10	Power Dissipation Capacitance	3.3	(Note 2)	-	15	-	_	_	pF
	(Figure 6)	5.0		-	18	-	-	-	

2. C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. (see Figure 6) C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).

AC Loading and Waveforms



 C_L includes load and stray capacitance Input PRR = 1.0 MHz, t_W = 500 ns



Input = AC Waveform; $t_r = t_f = 1.8$ ns; PRR = 10 MHz; Duty Cycle = 50%. Figure 6. I_{CCD} Test Circuit

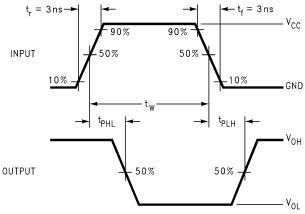


Figure 7. AC Waveforms

ORDERING INFORMATION

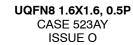
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NC7WZ132K8X	WZD2	8-Lead US8, JEDEC MO-187, Variation CA 3.1 mm Wide	3000 / Tape & Reel
NC7WZ132K8X-L22236	WZD2	8-Lead US8, JEDEC MO-187, Variation CA 3.1 mm Wide	3000 / Tape & Reel
NC7WZ132L8X	T5	8-Lead MicroPak, 1.6 mm Wide	5000 / Tape & Reel
NC7WZ132L8X-L22185	T5	8-Lead MicroPak, 1.6 mm Wide	5000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

3. All packages are lead free per JEDEC: J-STD-020B standard.

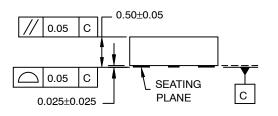
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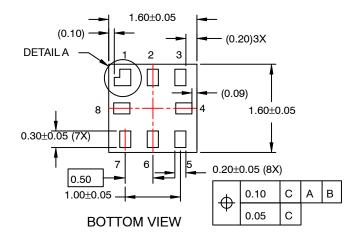


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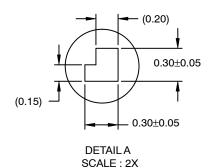
SIDE VIEW





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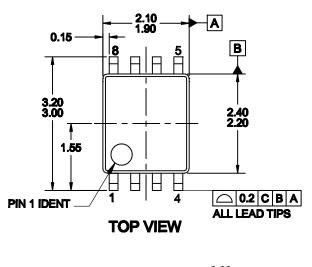
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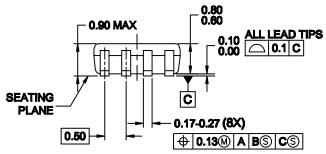
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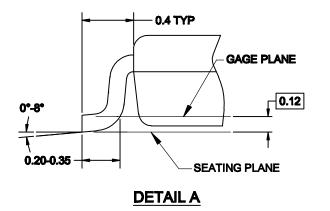
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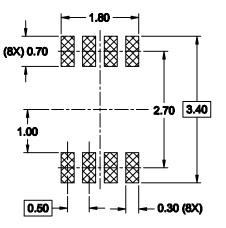
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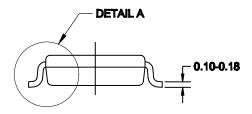




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